Plastic Power Transistors

NPN Silicon DPAK For Surface Mount Applications

Designed for high-gain audio amplifier applications.



• High DC Current Gain -

$$h_{FE} = 120 \text{ (Min)} @ I_C = 500 \text{ mA}$$

= 40 (Min) @ $I_C = 2 \text{ A}$

• Low Collector-Emitter Saturation Voltage -

$$V_{CE(sat)} = 0.3 \text{ Vdc (Max)} @ I_C = 1 \text{ A}$$

• High Current-Gain - Bandwidth Product -

$$f_T = 65 \text{ MHz (Min)} @ I_C = 100 \text{ mA}$$

• Epoxy Meets UL 94 V-0 @ 0.125 in

ESD Ratings: Human Body Model, 3B > 8000 V
 Machine Model, C > 400 V

• Pb-Free Package is Available

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Base Voltage	V _{CB}	50	Vdc
Collector-Emitter Voltage	V _{CEO}	50	Vdc
Emitter-Base Voltage	V _{EB}	5	Vdc
Collector Current Continuous Peak	IC	2 3	Adc
Base Current	I _B	0.4	Adc
Total Device Dissipation @ T _C = 25°C Derate above 25°C	P _D	15 0.1	W W/°C
Total Device Dissipation @ T _A = 25°C* Derate above 25°C	P _D	1.68 0.011	W W/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +175	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance Junction-to-Case Junction-to-Ambient*	$R_{ heta JC} \ R_{ heta JA}$	10 89.3	°C/W

^{*}These ratings are applicable when surface mounted on the minimum pad sizes recommended.

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ON Semiconductor®

http://onsemi.com

SILICON POWER TRANSISTORS 2 AMPERES 50 VOLTS 15 WATTS

MARKING DIAGRAM



DPAK CASE 369C STYLE 1



Y = Year WW = Work Week G = Pb-Free Device

ORDERING INFORMATION

Device	Package	Shipping [†]
NJD2873T4	DPAK	2500 Units / Reel
NJD2873T4G	DPAK (Pb-Free)	2500 Units / Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS	•		•	
Collector-Emitter Sustaining Voltage (Note 1) (I _C = 10 mAdc, I _B = 0)	V _{CEO(sus)}	50	-	Vdc
Collector Cutoff Current (V _{CB} = 50 Vdc, I _E = 0)	Ісво	-	100	nAdc
Emitter Cutoff Current (V _{BE} = 5 Vdc, I _C = 0)	I _{EBO}	-	100	nAdc
ON CHARACTERISTICS	•		•	
DC Current Gain (Note 1) $ \begin{aligned} &(I_C = 0.5 \text{ A, V}_{CE} = 2 \text{ V}) \\ &(I_C = 2 \text{ Adc, V}_{CE} = 2 \text{ Vdc}) \\ &(I_C = 0.75 \text{ Adc, V}_{CE} = 1.6 \text{ Vdc, } -40^{\circ}\text{C} \leq T_J \leq 150^{\circ}\text{C}) \end{aligned} $	h _{FE}	120 40 80	360 - 360	-
Collector-Emitter Saturation Voltage (Note 1) (I _C = 1 A, I _B = 0.05 A)	V _{CE(sat)}	-	0.3	Vdc
Base-Emitter Saturation Voltage (Note 1) (I _C = 1 A, I _B = 0.05 Adc)	V _{BE(sat)}	-	1.2	Vdc
Base-Emitter On Voltage (Note 1) $ \begin{aligned} &\text{(I}_C = 1 \text{ Adc, V}_{CE} = 2 \text{ Vdc)} \\ &\text{(I}_C = 0.75 \text{ Adc, V}_{CE} = 1.6 \text{ Vdc, } -40^{\circ}\text{C} \leq \text{T}_J \leq 150^{\circ}\text{C)} \end{aligned} $	V _{BE(on)}		1.2 0.95	Vdc
DYNAMIC CHARACTERISTICS				
Current-Gain - Bandwidth Product (Note 2) (I _C = 100 mAdc, V _{CE} = 10 Vdc, f _{test} = 10 MHz)	f _T	65	-	MHz
Output Capacitance (V _{CB} = 10 Vdc, I _E = 0, f = 0.1 MHz)	C _{ob}	-	80	pF

^{1.} Pulse Test: Pulse Width = 300 μ s, Duty Cycle \approx 2%. 2. f_T = $|h_{fe}| \bullet f_{test}$.

TYPICAL CHARACTERISTICS

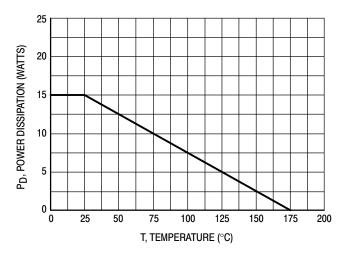


Figure 1. Power Derating

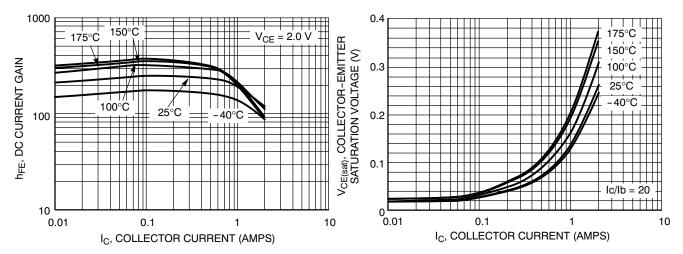


Figure 2. DC Current Gain

Figure 3. Collector-Emitter Saturation Voltage

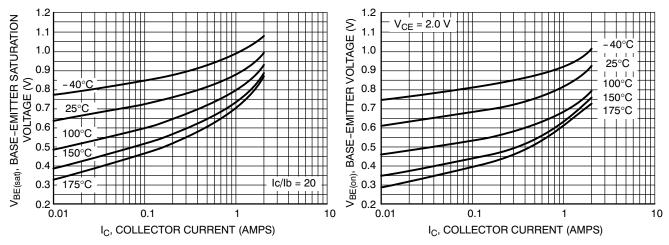


Figure 4. Base-Emitter Saturation Voltage

Figure 5. Base-Emitter Voltage

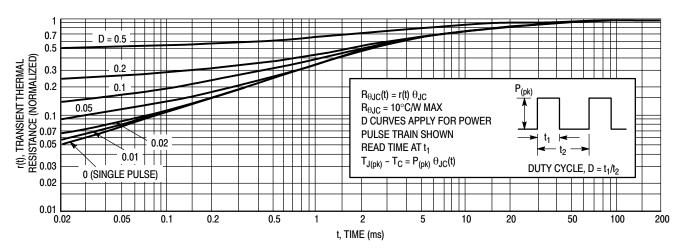
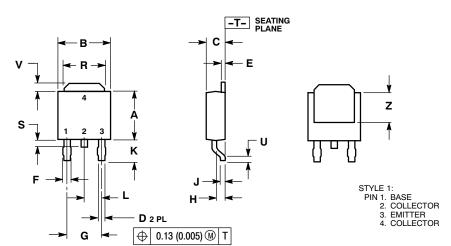


Figure 6. Thermal Response

PACKAGE DIMENSIONS

DPAK CASE 369C-01 ISSUE O

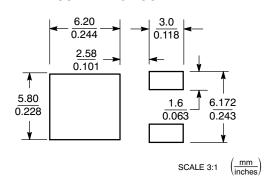


NOTES

- 1. DIMENSIONING AND TOLERANCING
- PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.235	0.245	5.97	6.22
В	0.250	0.265	6.35	6.73
С	0.086	0.094	2.19	2.38
ם	0.027	0.035	0.69	0.88
Е	0.018	0.023	0.46	0.58
F	0.037	0.045	0.94	1.14
G	0.180	0.180 BSC		BSC
Ŧ	0.034	0.040	0.87	1.01
7	0.018	0.023	0.46	0.58
K	0.102	0.114	2.60	2.89
٦	0.090	BSC	2.29	BSC
R	0.180	0.215	4.57	5.45
s	0.025	0.040	0.63	1.01
U	0.020		0.51	
٧	0.035	0.050	0.89	1.27
Z	0.155		3.93	

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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